

# PDTA143ZU

50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$ 

**23 January 2024** 

**Product data sheet** 

## 1. General description

PNP Resistor-Equipped Transistor (RET) in a small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTC143ZU

## 2. Features and benefits

- · 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

## 3. Applications

- · Digital application in automotive and industrial segments
- Cost-saving alternative for BC847/857 series in digital applications
- · Controlling IC inputs
- · Switching loads

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	

[1] See section "Test information" for resistor calculation and test conditions



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# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	□ 3	
2	GND	ground (emitter)		R <sub>1</sub> O
3	0	output (collector)	SC-70 (SOT323)	R2 GND sym003

# 6. Ordering information

## **Table 3. Ordering information**

Type number Package					
	Name	Description	Version		
PDTA143ZU	SC-70	plastic, surface-mounted package; 3 leads; 1.3 mm pitch; 2 mm x 1.25 mm x 0.95 mm body	SOT323		

# 7. Marking

### Table 4. Marking codes

Type number	Marking code[1]
PDTA143ZU	847

<sup>[1] % =</sup> placeholder for manufacturing site code

# 8. Limiting values

### Table 5. Limiting values

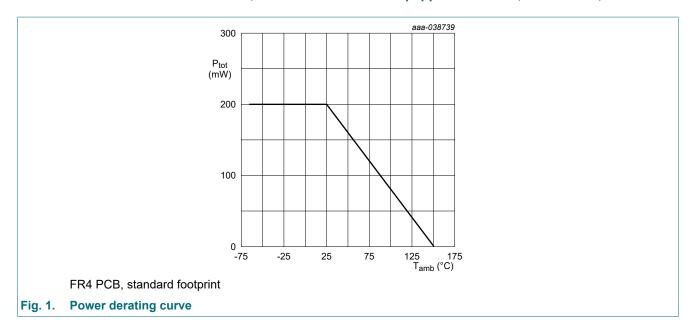
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
$V_{CEO}$	collector-emitter voltage	open base		-	-50	V
$V_{EBO}$	emitter-base voltage	open collector		-	-5	V
VI	input voltage			-30	5	V
Io	output current			-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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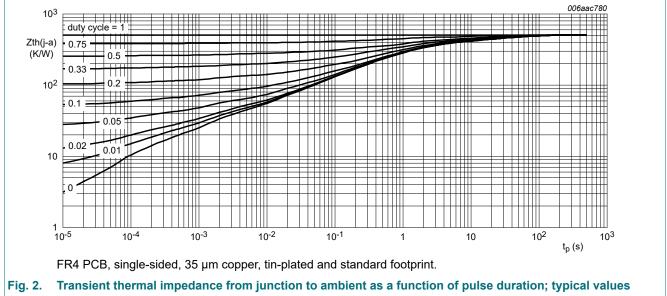


## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		[1]	-	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



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## 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 °C$		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>C</sub> = 0 A; I <sub>E</sub> = 100 μA; T <sub>amb</sub> = 25 °C		-5	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
I <sub>CEO</sub> collector-emitter cut-off	collector-emitter cut-off	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-1	μΑ
	current	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-170	μΑ
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; T <sub>amb</sub> = 25 °C		100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	-100	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -100 μA; T <sub>amb</sub> = 25 °C		-	-0.6	-0.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}$ = -0.3 V; $I_{C}$ = -5 mA; $T_{amb}$ = 25 °C		-1.3	-0.9	-	V
R1	bias resistor 1 (input)	T <sub>amb</sub> = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	180	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions
- [2] Characteristics of built-in transistor

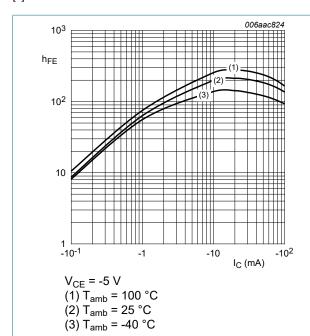


Fig. 3. DC current gain as a function of collector current; typical values

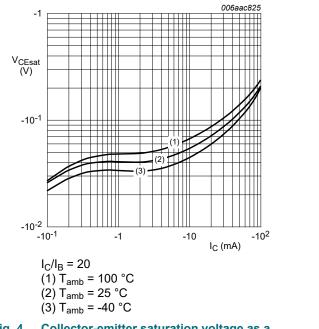
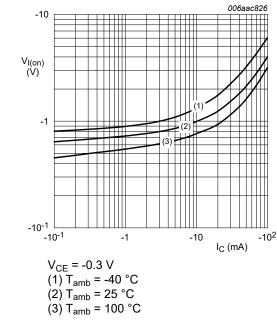
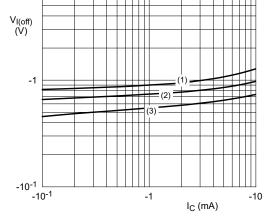


Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

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V<sub>CE</sub> = -5 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 5. On-state input voltage as a function of collector | Fig. 6. current; typical values



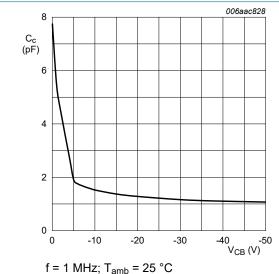
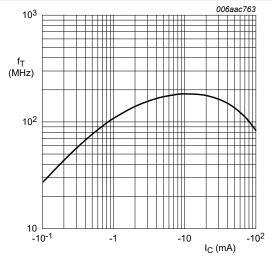


Fig. 7. Collector capacitance as a function of collector- Fig. 8. base voltage; typical values



Transition frequency as a function of collector current; typical values of built-in transistor

 $V_{CE}$  = -5 V;  $T_{amb}$  = 25 °C

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## 11. Test information

## **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

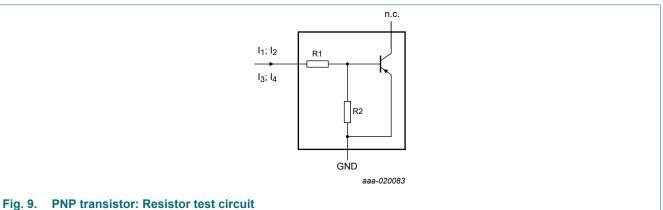
### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



#### ig. 5. PNP transistor. Resistor test circuit

#### **Resistor test conditions**

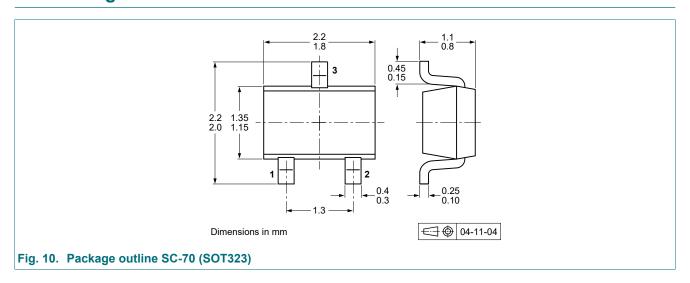
**Table 8. Resistor test conditions** 

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	14
PDTA143ZU	4.7	47	-90 μA	-140 µA	55 µA	105 μΑ

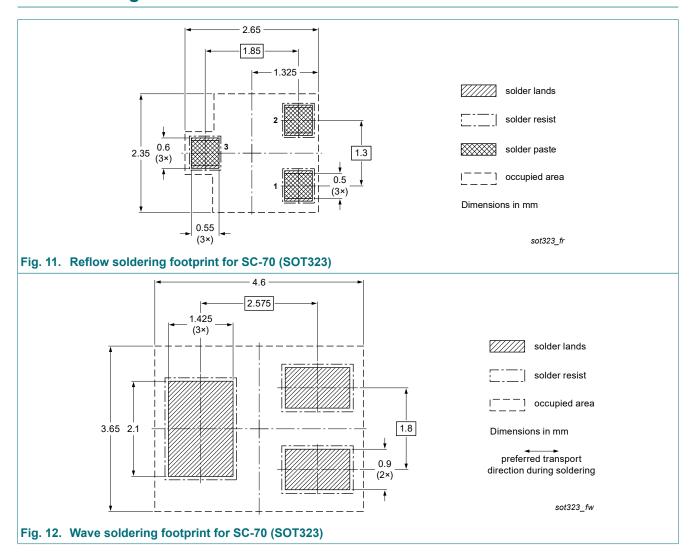
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# 12. Package outline



# 13. Soldering



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# 14. Revision history

### Table 9. Revision history

Table of Horiotell Inletery				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PDTA143ZU v.8	20240123	Product data sheet	-	PDTA143Z_SER v.7
Modification:	•	sheet reduced to single type da mation removed.	ata sheet.	
PDTA143Z_SER v.7	20111205	Product data sheet	-	PDTA143Z_SERIES v.6
PDTA143Z_SERIES v.6	20040805	Product data sheet	-	PDTA143Z_SERIES v.5
PDTA143Z_SERIES v.5	20030908	Product specification	-	PDTA143Z_SERIES v.4
PDTA143Z_SERIES v.4	20030410	Product specification	-	-

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## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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